

Sonic Fast Recovery Diode

$$V_{RRM} = 4500 \text{ V}$$

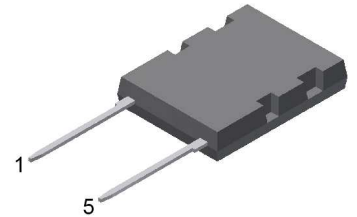
$$I_{F80} = 43 \text{ A}$$

$$t_{rr} = 1450 \text{ ns}$$

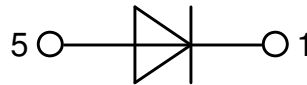
High Performance Fast Recovery Diode
Low Loss and Soft Recovery
Single Diode

Part number

DHG40I4500KO



Backside: Isolated
see important note page 3



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: ISOPLUS264

- Isolation Voltage: 4200 V~
- Industry convenient outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

Terms and Conditions of Usage

The data contained in this product data sheet is exclusively intended for technically trained staff. The user will have to evaluate the suitability of the product for the intended application and the completeness of the product data with respect to his application. The specifications of our components may not be considered as an assurance of component characteristics. The information in the valid application- and assembly notes must be considered. Should you require product information in excess of the data given in this product data sheet or which concerns the specific application of your product, please contact your local sales office.

Due to technical requirements our product may contain dangerous substances. For information on the types in question please contact your local sales office.

Should you intend to use the product in aviation, in health or life endangering or life support applications, please notify. For any such application we urgently recommend

- to perform joint risk and quality assessments;

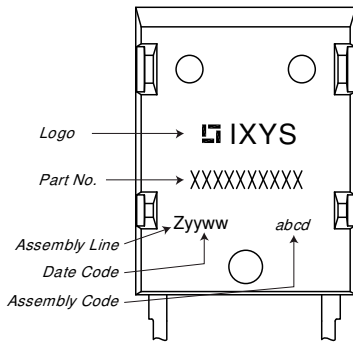
- the conclusion of quality agreements;

- to establish joint measures of an ongoing product survey, and that we may make delivery dependent on the realization of any such measures.

| Fast Diode | | | | Ratings | | | |
|------------|--|--|-------------------------|---------|------|------------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 4500 | V | |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 4500 | V | |
| I_R | reverse current, drain current | $V_R = 4500 V$ | $T_{VJ} = 25^{\circ}C$ | | 100 | μA | |
| | | $V_R = 4500 V$ | $T_{VJ} = 125^{\circ}C$ | | 2 | mA | |
| V_F | forward voltage drop | $I_F = 50 A$ | $T_{VJ} = 25^{\circ}C$ | | 3.00 | V | |
| | | $I_F = 100 A$ | | | | V | |
| | | $I_F = 50 A$ | $T_{VJ} = 125^{\circ}C$ | | 3.50 | V | |
| | | $I_F = 100 A$ | | | | V | |
| I_{FAV} | average forward current | $T_C = 80^{\circ}C$ rectangular $d = 1.0$ | $T_{VJ} = 150^{\circ}C$ | | 43 | A | |
| V_{FO} | threshold voltage | } for power loss calculation only | $T_{VJ} = 150^{\circ}C$ | | 2.20 | V | |
| r_F | slope resistance | | | | 24 | m Ω | |
| R_{thJC} | thermal resistance junction to case | | | | 0.5 | K/W | |
| R_{thCH} | thermal resistance case to heatsink | | | 0.15 | | K/W | |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}C$ | | 250 | W | |
| I_{FSM} | max. forward surge current | $t = 10 ms; (50 Hz), sine; V_R = 0 V$ | $T_{VJ} = 45^{\circ}C$ | | 600 | A | |
| C_J | junction capacitance | $V_R = 1800 V \quad f = 1 MHz$ | $T_{VJ} = 25^{\circ}C$ | | 13 | pF | |
| I_{RM} | max. reverse recovery current | } $I_F = 50 A; V_R = 2800 V$ $-di_F / dt = 800 A/\mu s$ | $T_{VJ} = 25^{\circ}C$ | | 80 | A | |
| | | | $T_{VJ} = 125^{\circ}C$ | | 82 | A | |
| t_{rr} | reverse recovery time | | $T_{VJ} = 25^{\circ}C$ | | 1450 | ns | |
| | | | $T_{VJ} = 125^{\circ}C$ | | 2200 | ns | |

| Package ISOPLUS264 | | Ratings | | | | |
|--------------------|--|----------------------|------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 70 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C |
| T_{op} | operation temperature | | -40 | | 125 | °C |
| T_{stg} | storage temperature | | -40 | | 150 | °C |
| Weight | | | | 10 | | g |
| F_C | mounting force with clip | | 20 | | 120 | N |
| $d_{Spp/App}$ | creepage distance on surface striking distance through air | terminal to terminal | 13.8 | | | mm |
| $d_{Spb/Apb}$ | | terminal to backside | 5.0 | | | mm |
| V_{ISOL} | isolation voltage | t = 1 second | 4200 | | | V |
| | | t = 1 minute | 3000 | | | V |

Product Marking



Part description

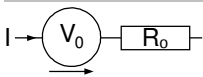
- D = Diode
- H = Sonic Fast Recovery Diode
- G = extreme fast
- 40 = Current Rating [A]
- I = Single Diode
- 4500 = Reverse Voltage [V]
- KO = ISOPLUS264 (2HV)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DHG40I4500KO | DHG40I4500KO | | | |

Equivalent Circuits for Simulation

* on die level

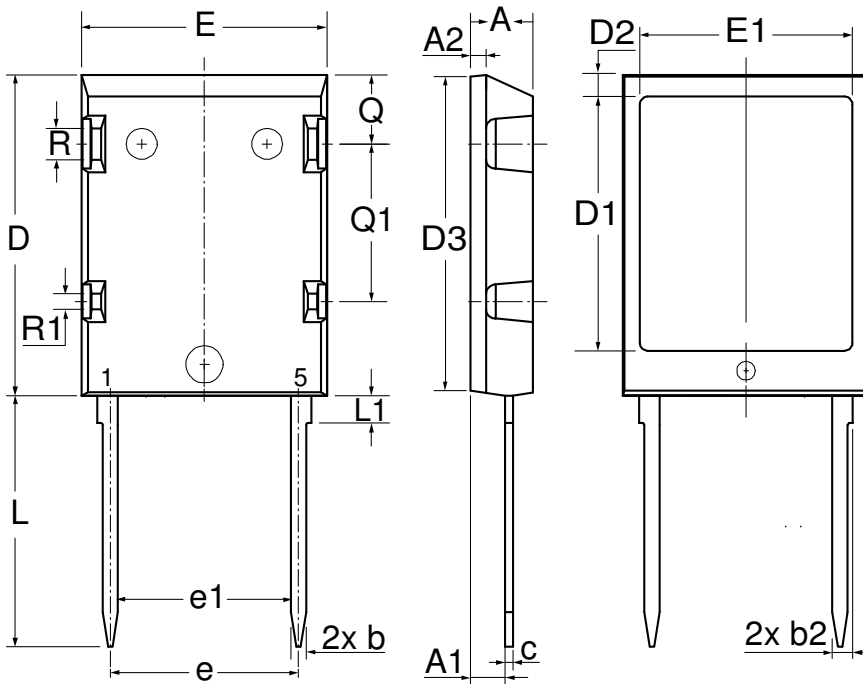
$T_{VJ} = 150\text{ °C}$



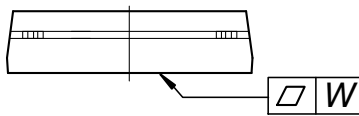
Fast Diode

| | | | |
|--------------|--------------------|-----|----|
| $V_{0\ max}$ | threshold voltage | 2.2 | V |
| $R_{0\ max}$ | slope resistance * | 24 | mΩ |

Outlines ISOPLUS264



| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | min | max | min | max |
| A | 4.83 | 5.21 | 0.190 | 0.205 |
| A1 | 2.59 | 3.00 | 0.102 | 0.118 |
| A2 | 1.17 | 1.40 | 0.046 | 0.055 |
| b | 1.14 | 1.40 | 0.045 | 0.055 |
| b2 | 1.60 | 1.83 | 0.063 | 0.072 |
| c | 0.51 | 0.74 | 0.020 | 0.029 |
| D | 25.91 | 26.42 | 1.020 | 1.040 |
| D1 | 20.34 | 20.85 | 0.801 | 0.821 |
| D2 | 1.65 | 2.03 | 0.065 | 0.080 |
| D3 | 25.29 | 25.78 | 1.000 | 1.020 |
| E | 19.56 | 20.29 | 0.770 | 0.799 |
| E1 | 16.97 | 17.53 | 0.668 | 0.690 |
| e | 15.24 | BSC | 0.600 | BSC |
| e1 | 14.10 | BSC | 0.555 | BSC |
| L | 19.81 | 20.83 | 0.780 | 0.820 |
| L1 | 2.03 | 2.59 | 0.080 | 0.102 |
| Q | 5.33 | 5.97 | 0.210 | 0.235 |
| Q1 | 12.45 | 13.03 | 0.490 | 0.513 |
| R | 3.81 | 4.57 | 0.150 | 0.180 |
| R1 | 2.54 | 3.30 | 0.100 | 0.130 |
| W | - | 0.10 | - | 0.004 |

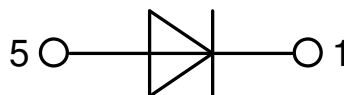


Die konvexe Form des Substrates ist typ. < 0.05 mm über der Kunststoffoberfläche der Bauteilunterseite
 The convexbow of substrate is typ. < 0.05 mm over plastic surface level of device bottom side

Important note:

External clearances between pins and between pins and tab may be insufficient to prevent flash over under all conditions. It is the customer's responsibility to apply additional insulation appropriate to the application. ISOPLUS264 is designed to isolate a max continuous operation voltage (DC) of 1700 V. The peak test voltage of 4200 V assures safety for transient voltages only. The package is not tested for partial discharge. If the product is used outside the package design voltage range the customer must use additional electrical insulation. Extra insulation layers should be used both between the tab and any heatsink and between any conducting clip and the top surface of the package particularly when metal parts (such as a heatsink or a clip) are in contact. Please note that the intention of this package is to provide customers with an encapsulated die for high voltage application but the responsibility rests entirely with the customer to ensure for safe operation. Bodily injury cannot be excluded if this warning is disregarded. Device implementation is the end user's responsibility.

For a low FIT rate over lifetime failures due to SEB (Single Event Burnout) and an adequate voltage derating should be considered.



Fast Diode

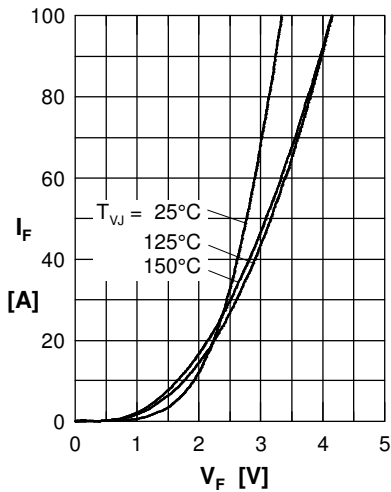


Fig. 1 Forward current I_F versus V_F

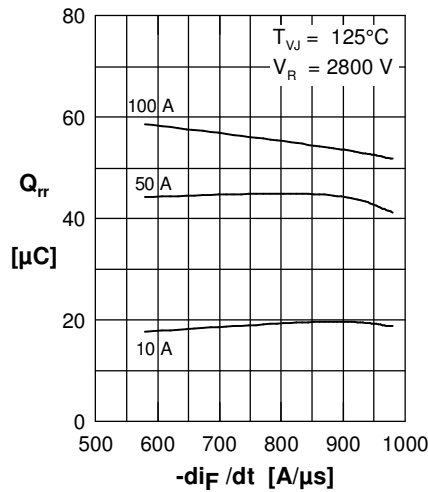


Fig. 2 Typ. reverse recov. charge Q_{rr} versus $-di_F/dt$

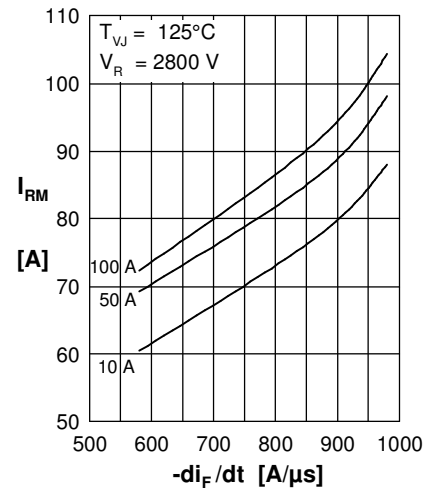


Fig. 3 Typ. reverse recov. current I_{RM} versus $-di_F/dt$

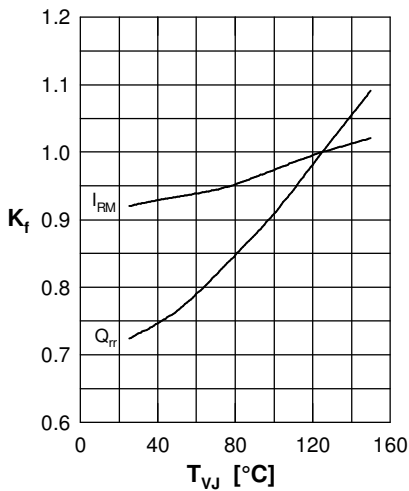


Fig. 4 Typ. dynamic parameters Q_{rr} , I_{RM} versus T_{VJ}

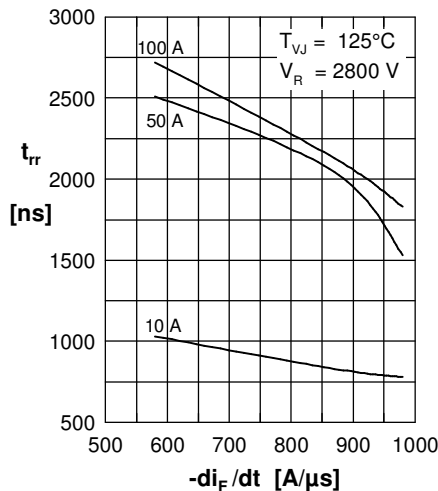


Fig. 5 Typ. reverse recov. time t_{rr} versus $-di_F/dt$

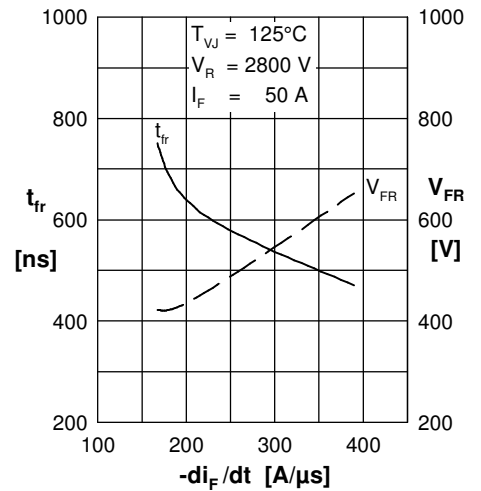


Fig. 6 Typ. forward recov. voltage V_{FR} & time t_{fr} versus di_F/dt

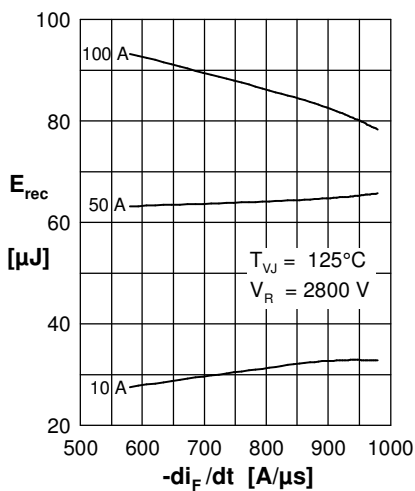


Fig. 7 Typ. recovery energy E_{rec} versus $-di_F/dt$

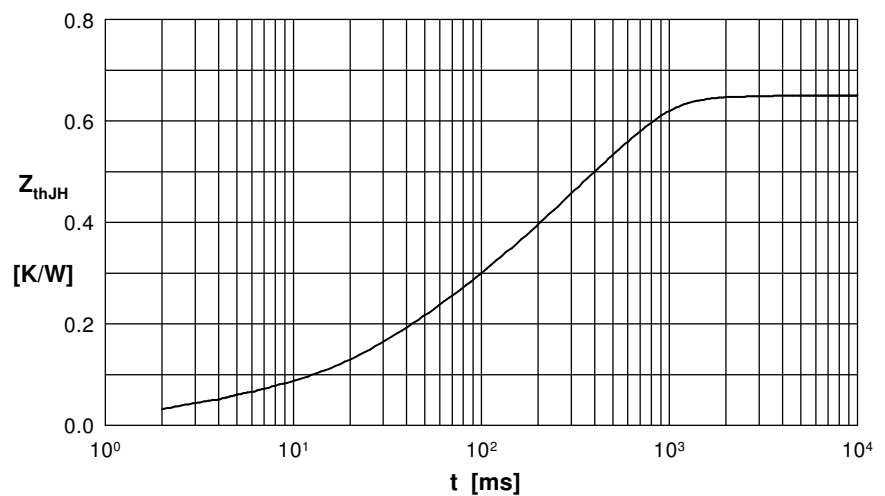


Fig. 8 Typical transient thermal impedance junction to heatsink

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С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

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- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
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- Комплексную поставку.
- Работу по проектам и поставку образцов.
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- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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